**Planning**

**(18th – 22nd October)**

**MONDAY**

* MBE growth: GaN overgrowth on pillars on GaN/sapphire grown by us (2 samples) (**Chinese** project)

**TUESDAY**

* MBE growth: GaN overgrowth on pillars on GaN/sapphire grown by us or AlN growth on previous samples (**Chinese** project)

**WEDNESDAY**

* MBE growth: AlN growth on previous samples (**Chinese** project).
* Processing: ICP etching (pillars) of last week samples (**Chinese** project).
* MBE meeting? Time?

**THURSDAY**

* MBE growth: GaN growth on TPR mask depending on the meeting (**TPR** project).
* Processing: e-beam litho, in 1 or 2 samples, for nanorods on GaN/sapphire (**Chinese** project).

**FRIDAY**

* MBE growth: GaN on pillars on GaN/sapphire or continuation of one of the previous samples of GaN NCs on GaN/sapphire or Al(Ga)N growth on some of the previous pillars samples (**Chinese** project).
* Processing: long e-beam litho (for weekend) for nanorods on GaN/sapphire (**Chinese** project).

SEM characterization of samples whenever it is necessary and depending on system availability.

Processing (lift-off, cleaning...) of etched pillars.